

1214-32L 32 Watts, 36 Volts Pulsed Radar at 1.2-1.4 GHz

GENERAL DESCRIPTION

The 1214-32L is an internally matched, COMMON BASE transistor capable of providing 32 Watts of pulsed RF output power at 5 milliseconds pulse width, 20% duty factor across the band 1200 to 1400 MHz. This hermetically soldersealed transistor is specifically designed for LBand radar applications. It utilizes gold metallization and diffused emitter ballasting to provide high reliability and supreme ruggedness.

ABSOLUTE MAXIMUM RATINGS

| Maximum Power Dissipation Device Dissipation @ 25°C ¹ Maximum Voltage and Current | 125 W |
|---|-----------------------|
| Collector to Base Voltage (BV _{ces}) Emitter to Base Voltage (BV _{ebo}) Collector Current (I _c) Maximum Temperatures | 50 V 3.5 V 5 A |
| Storage Temperature -65 to Operating Junction Temperature | to +200 °C +200 °C |

CASE OUTLINE 55AW-1

ELECTRICAL CHARACTERISTICS @ 25°C

| SYMBOL | CHARACTERISTICS | TEST CONDITIONS | MIN | ТҮР | MAX | UNITS |
|--|--------------------------------------|------------------------------|-----|-----|-------|-------|
| P _{out} ¹ Power Output | | F = 1200-1400 MHz | | | 41 | W |
| Pg Power Gain | | Pin = 5.3 W | 7.8 | | 8.9 | dB |
| η_c | Collector Efficiency | Pulse Width = 5 mS | 42 | 45 | | % |
| R _L Return Loss | | Duty Factor = 20% | -9 | | | dB |
| Pd Pulse Droop | | | | | 0.5 | dB |
| VSWR ¹ | Load Mismatch Tolerance ¹ | F=1200 MHz, Pin=5.3 W | | | 3.0:1 | |

FUNCTIONAL CHARACTERISTICS @ 25°C

| BV _{ebo} | Emitter to Base Breakdown | Ie = 15 mA | 3.5 | | V |
|-------------------|--------------------------------|-------------------|-----|-----|------|
| BV _{ces} | Collector to Emitter Breakdown | Ic = 100 mA | 50 | | V |
| h _{FE} | DC – Current Gain | Vce = 5V, Ic = 1A | 20 | | |
| θjc^1 | Thermal Resistance | | | 1.4 | °C/W |

NOTES: 1. Pulse condition of 5 mS, 20%

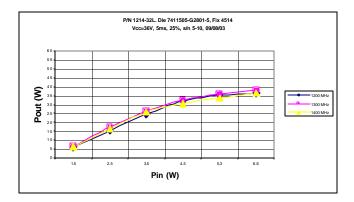
Rel 5: March 2005

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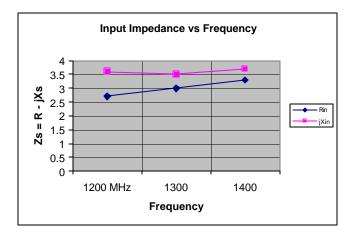
1214-32L

Performance Curves

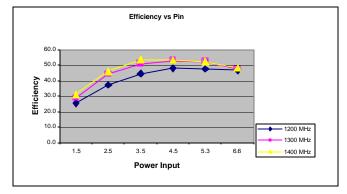
Power Output vs Power Input



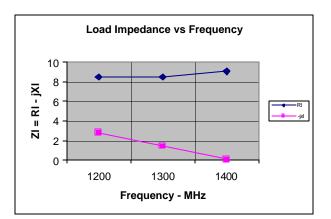
Input Impedance

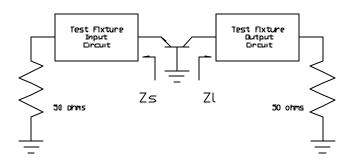


Efficiency vs Power Input



Load Impedance



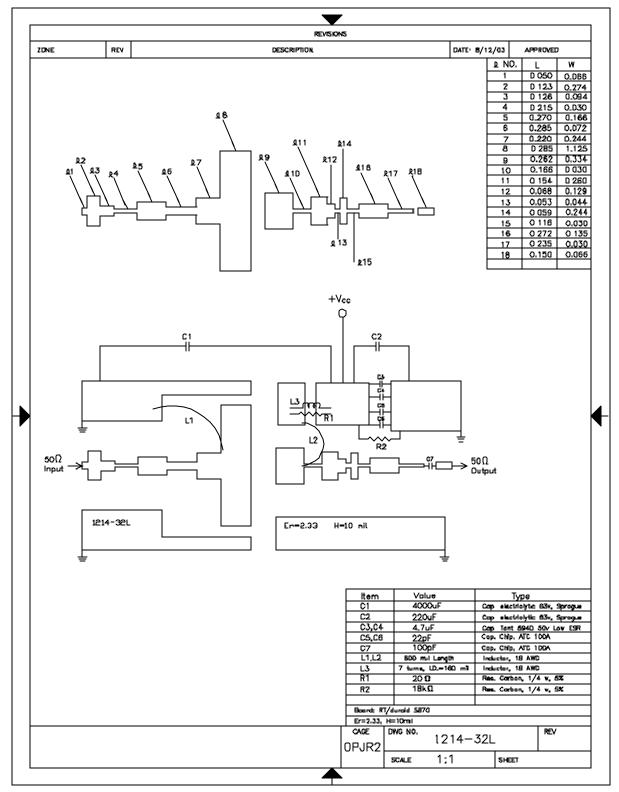


| Impedance | | |
|-----------|----------|------------|
| Freq | Zs | ZI |
| 1200 | 2.7-j3.6 | 8.5-j2.8 |
| 1300 | 3-j3.5 | 8.5-j1.44 |
| 1400 | 3.3-j3.7 | 9.07-j0.08 |

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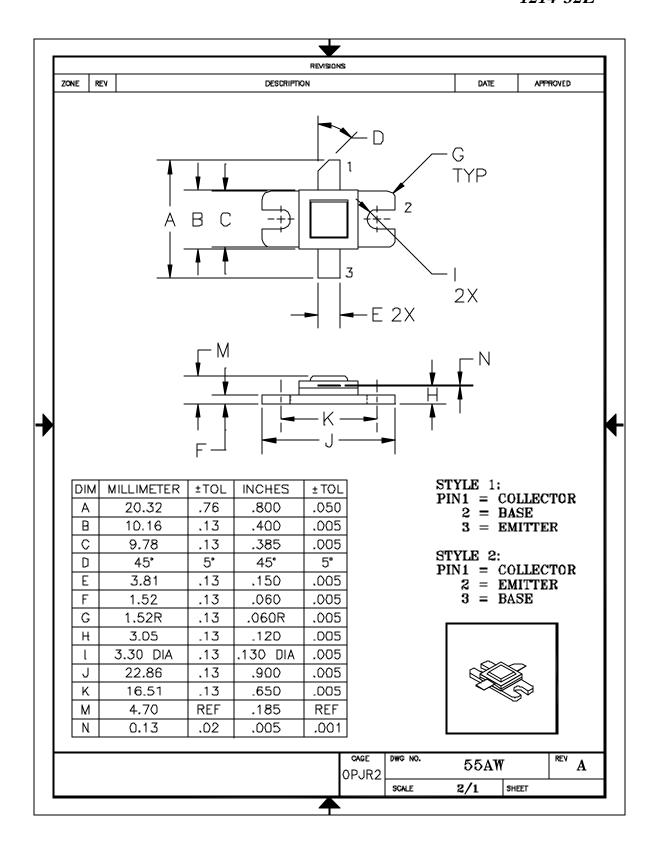
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